Seat No.:	Enrolment No.

GUJARAT TECHNOLOGICAL UNIVERSITY

		BE - SEMESTER-I & II(NEW) EXAMINATION – WINTER 2022	
	0	Code:3110016 Date:16-03-20	023
	U	Name:Basic Electronics	=0
		0:30 AM TO 01:00 PM Total Marks	5:70
Instr	uction 1.	Attempt all questions.	AC
	3.	Figures to the right indicate full marks.	7
	4.	Simple and non-programmable scientific calculators are allowed.	Mark
0.1	(a)		03
Q.1	(a) (b)	Define between insulator, conductor and semiconductor. What is Zener breakdown? What is avalanche breakdown? Compare both	03
	(10)	the type of breakdown.	0.1
	(c)	Explain full wave bridge rectifier with neat diagram.	07
	(c)	Explain full wave original rectifier with heat diagram.	07
Q.2	(a)	Design and explain basic NAND gate using DTL logic.	03
~-	(b)	Discuss different types of diodes. Describe process of testing diode with	04
		multi meter.	
	(c)	Write a short note: V-I characteristic of P-N junction diode.	07
	(c)	OR Why biasing is important in transistor? Explain voltage divider bias with	07
	(c)	diagram.	07
		× × × × × × × × × × × × × × × × × × ×	
Q.3	(a)	Explain about DC load line of transistor.	03
	(b)	Explain PIN photo diode.	04
	(c)	Draw and explain input and output characteristic of transistor in common emitter configuration.	07
		OR	
Q.3	(a)	What is varactor diode? How capacitance of a diode varies with reverse	03
		voltage?	
	(b)	Explain the selection of a Q point for a transistor bias circuit and discuss	04
	(c)	the limitations on the output voltage swing. Compare CB and CC configuration with respect to different transistor	07
	(c)	characteristics.	07
Q.4	(a)	Draw voltage multiplier circuit.	03
	(b)	Explain (i) Unipolar device (ii) Transconductance.	04
	(c)	Explain application of transistor as a switch. OR	07
Q.4	(a)	Explain FET as an Amplifier.	03
	(b)	Explain why NAND and NOR gate are called universal gate?	04
	(c)	Explain the Depletion region and drain characteristics of n channel JFET.	07
	0		
Q.5	(a)	Among TTL and CMOS digital logic family which one is better and why?	03
	(b)	Draw and explain the self-bias circuit of FET.	04
	(c)	Write a short note: E-Type MOSFET.	07
0.5		OR	0.7
Q.5	(a) (b)	Derive the relation between current gain α and β. What are the advantages of N-Channel MOSFET over P-Channel	03 04
	(0)	What are the advantages of Wellander Wood 11 Chainer	UT

(c) Draw symbol and explain truth table of all basic logic gates.

